Key Features



Product Description

WP-11 Gold plated housing.

WMA04A integrates WanTcom proprietary power

amplifier technology, high frequency micro

electronic assembly techniques, and high reliability

design to realize optimum low noise figure,

wideband, high linearity, and unconditional stable

performances together. With single DC operation,

the amplifier has 4.5 Ω low input impedance and

excellent low noise at 50 Ω source impedance, Z_s.

The amplifier has standard SMA connectorized



Applications

- · Magnetic Resonance Imaging
- RF Measurement
- Medical Equipment
- Current Sensor



- 4.0 MHz Frequency
- 4.5 Ohm Input Impedance
- 12.0 dBm Output P_{1dB}
- 28.0 dB Gain, $Z_s = 50 \Omega$
- 22.0 dBm Output IP₃
- 1.22:1 Output VSWR
- Single power supply
- >68 years MTBF
- RoHS compliant
- Meet MIL-STD-202g

Specifications

Summary of the electrical specifications WMA04A at room temperature

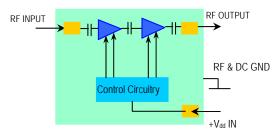
Index	Testing Item	Symbol	Test Constraints	Min	Nom	Max	Unit
1	Gain	S ₂₁	4.0 MHz	27.5	28	28.5	dB
2	Gain Variation	ΔG	4.0 +/ 0.1 MHz		+/- 0.1	+/-0.3	dB
3	Noise Figure	NF	4.0 MHz		TBD		dB
4	Input Impedance	RE[Zin]	4.0 MHz	3.0	4.5	6.0	Ohm
		IM[Zin]	4.0 MHz	-3.0	0	3.0	
5	Output VSWR	SWR ₂	4.0 MHz, 50 Ω Impedance		1.15:1	1.22:1	Ratio
6	Reverse Isolation	S ₁₂	0.1 – 500 MHz	48	50		dB
7	Output Power 1dB Compression Point	P _{1dB}	4.0 MHz	8	12		dBm
8	Output-Third-Order Interception Point	IP ₃	Two-Tone, 0 dBm each, 0.5 MHz Separation	18	24		dBm
10	Current Consumption	I _{dd}	V _{dd} = +10.0 V		16	20	mA
11	DC Power Supply Operating Voltage	V_{dd}		+7	+10	+15	V
12	Thermal Resistance	R _{th,c}	Junction to case			220	°C/W
13	Operating Temperature	To		+10		+60	°C
14	Maximum RF Input Power	P _{IN, MAX}	4.0 MHz, 10% Duty Cycle, $Z_s = 75 \Omega$			25	dBm
15	Saturate Recover Time	t _{sr}	10% to 90% from 20 dBm Pin		TBD		uS
16	ESD Protection, None Contact	V _{ESDN}	Output Port			16	kV
17	ESD Protection, Direct Contact	V _{ESD}	Output Port			6	kV

Absolute Maximum Ratings

Parameters	Units	Ratings
DC Power Supply Voltage	V	-0.5, 15V
Drain Current	mA	25
Total Power Dissipation	mW	250
Maximum RF Input Power, 3.0 MHz, 10% Duty Cycle, $Z_s = 50 \Omega$	dBm	25
Channel Temperature	°C	150
Storage Temperature	°C	-55 ~ 125
Operating Temperature	°C	0 ~ 60
Thermal Resistance	°C/W	220

Operation of this device above any one of these parameters may cause permanent damage.

Functional Block Diagram



Ordering Information

Typical Data:

Preliminary

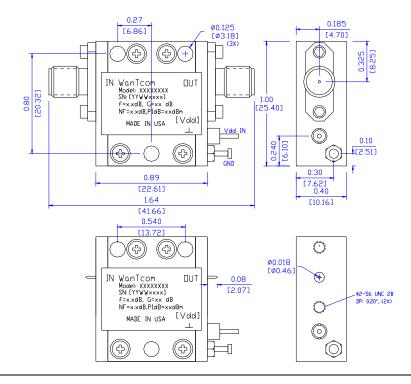
Outline, WP-11 Housing

UNITS: INCH [mm]
BODY: Brass

Finish: Gold Plating
RF Connector: SMA F Gold Field

Replaceable

V_{dd} PWR: Feed through



Application Notes:

A. SMA Torque Wrench Selection

Always use a torque wrench with $5 \sim 6$ inch-lb coupling torque setting for mating the SMA cables to the amplifier. Never use torque more than 8 inch-lb wrench for tightening the mating cable to the connector. Otherwise, the permanent damage will occur to the SMA connectors of the amplifier. 8710-1582 (5 inch-lb) is one of the ideal torque wrench choice from Agilent Technology.

B. DC Power Line Connection

Strip the insulation layer at the end of DC power supply wire. The stripped distance should be in the range of 0.100" to 0.200". The $24 \sim 26$ American Wire Gauge wire is suitable. Wound the stripped terminal wire about 1 to 2 turns on the DC feed thru center pin. Solder the wounded wire and the center pin together. Clean the soldering area by Q-tip with alcohol to remove the flux and residue.

Repeat the process to solder the DC return wire on the ground turret.

C. Mounting the Amplifier

Use three pieces of #4-40 with longer than 9/16" screws for mounting the amplifier on a metal-based chase. Flat and spring washers are needed to prevent the screw loosening during the shock and vibration. Always use the appropriate torque setting of the power screwdriver to mount them.
